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Hyperfast Rectifier, 8 A FRED Pt®



DPAK (TO-252AA)

PRIMARY CHARACTERISTICS									
I _{F(AV)}	8 A								
V _R	600 V								
V _F at I _F	1.3 V								
t _{rr} (typ.)	18 ns								
T _J max.	175 °C								
Package	DPAK (TO-252AA)								
Circuit configuration	Single								

FEATURES

- Hyperfast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 143 °C	8							
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	90	А						
Peak repetitive forward current	I _{FM}	$T_{C} = 143 \text{ °C}, f = 20 \text{ kHz}, d = 50 \text{ \%}$	16							
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
Forward voltage	V _F	I _F = 8 A	-	2.0	2.4	V				
		I _F = 8 A, T _J = 150 °C	-	1.3	1.8					
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	50					
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$		-	500	μA				
Junction capacitance	CT	V _R = 600 V	-	8	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH				

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RoHS

COMPLIANT

HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	0 A/μs, V _R = 30 V		21					
	+	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 10$	-	18	22	ns				
	t _{rr}	T _J = 25 °C		-	25	-	A			
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/µs	-	34	-				
Pools receivers ourrent	I _{RRM}	T _J = 25 °C		-	3.3	-				
Peak recovery current		T _J = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	4.8	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	39	-				
		T _J = 125 °C		-	90	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	AMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX.									
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	1.8	2.2	°C/W				
Approvimate weight				0.3		g				
Approximate weight				0.01		oz.				
Marking device		Case style DPAK (TO-252AA)	8EWH06FN							



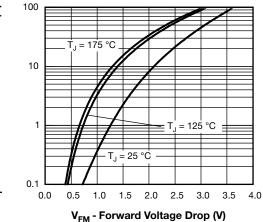


Fig. 1 - Typical Forward Voltage Drop Characteristics

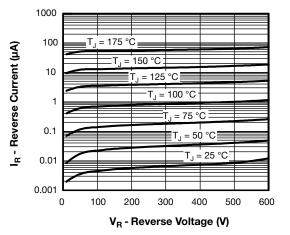


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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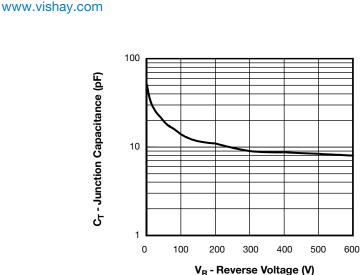


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

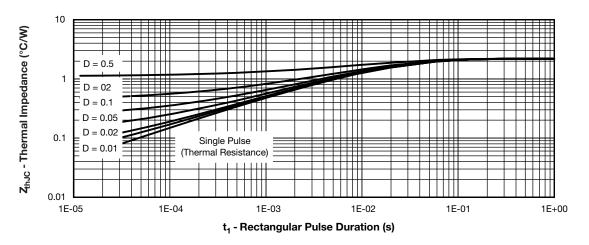


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

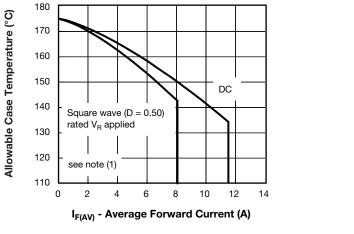


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

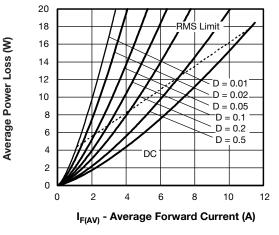


Fig. 6 - Forward Power Loss Characteristics

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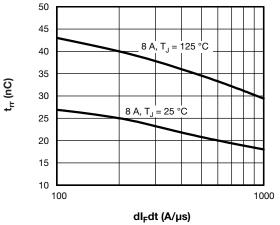
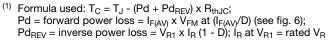


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





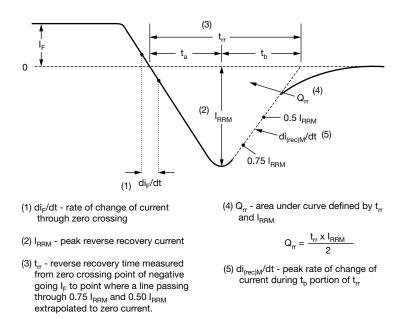
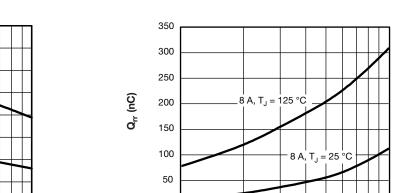


Fig. 9 - Reverse Recovery Waveform and Definitions



0

100

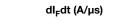


Fig. 8 - Typical Stored Charge vs. dl_F/dt

VS-8EWH06FN-M3

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1000

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ORDERING INFORMATION TABLE

Device code	vs-	8	Е	w	н	06	FN	TRL	-M3
		2	3	4	5	6	7	8	9
	1	· Visl	nay Sen	nicondu	ctors pro	oduct			
	2	- Cur	rent rati	ng (8 =	8 A)				
	3.			iguratio					
		E =	single o	diode					
	4	- Pac	kage id	entifier:					
		W =	D-PAK	(
	5	• H=	hyperfa	st recov	very				
	6	· Volt	tage rati	ng (06 =	= 600 V)				
	7 ·	· FN	= TO-25	52AA					
	8	• N	one = tu	ıbe					
		• TI	R = tape	e and ree	əl				
		• TI	RL = tap	e and r	eel (left	orienteo	d)		
		• TI	RR = tap	be and r	eel (righ	nt orient	ed)		
	9 -	- Env	rironmer	ntal digit	:				
		-M3	3 = Halo	gen-free	e, RoHS	-compli	ant, and	d termin	ations l

ORDERING INFORMATION (Example)										
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION								
VS-8EWH06FN-M3	75	Antistatic plastic tube								
VS-8EWH06FNTR-M3	2000	13" diameter reel								
VS-8EWH06FNTRL-M3	3000	13" diameter reel								
VS-8EWH06FNTRR-M3	3000	13" diameter reel								

LINKS TO RELATED DOCUMENTS									
Dimensions	www.vishay.com/doc?95627								
Part marking information	www.vishay.com/doc?95176								
Packaging information	www.vishay.com/doc?95033								
SPICE model	www.vishay.com/doc?96114								







D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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